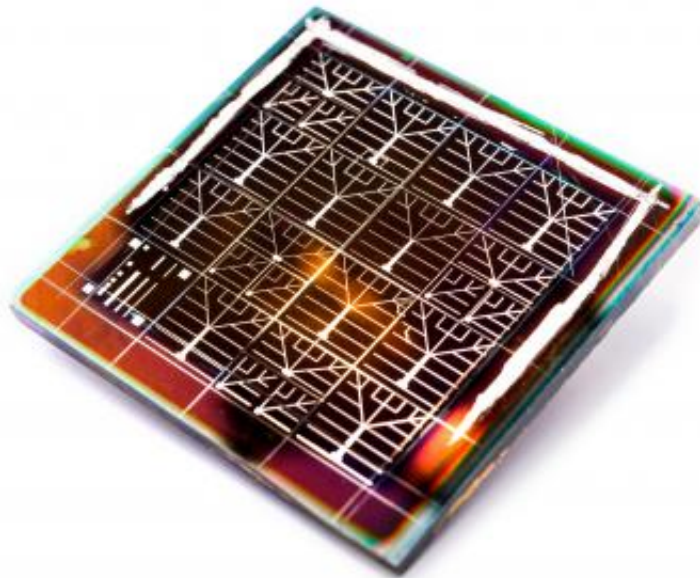


Solliance and imec achieve 9.7% efficiency with new thin-film CZTSe solar cell

July 4 2013



Thin-film CZTSe solar cell achieving 9.7% efficiency

At next week's Intersolar conference in San Francisco, imomec, imec's associated lab at the Hasselt University, and Solliance, the European R&D consortium that focuses on thin-film photovoltaic solar energy (PV), will present a CZTSe ($\text{Cu}_2\text{ZnSnSe}_4$)-based solar cell with 9.7 percent efficiency ($1 \times 1 \text{ cm}^2$, AM1.5G). This promising result is an important step bringing the solar industry closer to a sustainable

alternative for the highest efficiency thin-film solar cells in production, based on CIGS ($\text{Cu}(\text{In},\text{Ga})(\text{S},\text{Se})_2$).

CZTSe is an emerging alternative solar cell absorber in thin-film solar cells, similar to CZTS ($\text{Cu}_2\text{ZnSnS}_4$). Unlike CIGS, CZTS and CZTSe do not suffer from abundance issues. At 1.5-1.6eV for CZTS, and 0.9eV for CZTSe, their bandgaps make a combined material system ideal for a multi-junction, thin-film solar cell that rivals the efficiency of CIGS cells (about 20 percent). Imomec, imec and Solliance have defined a path towards further improving the layers and cell structures of CZTSe and CZTS absorbers aiming at developing a multi junction CZTS/CZTSe solar cell with 20 percent cell efficiency. The presented CZTSe solar cell is an important step forward to reach this goal.

Imec/imomec fabricated the CZTSe layers by sputtering Cu, Zn and Sn metal layers on a Molybdenum-on-glass substrate and subsequent annealing in an H_2Se containing atmosphere, achieving 9.7 percent efficiency. The resulting polycrystalline absorber layers are only $1\mu\text{m}$ thick, with a typical grain size of about $1\mu\text{m}$. The samples were then processed at Helmholtz Zentrum Berlin into solar cells using a standard process flow for thin film solar cells and finished with a metal grid and anti-reflective coating at imec. The highest [efficiency](#) obtained on a $1\text{x}1\text{cm}^2$ cell was 9.7 percent, with a maximum short circuit current of $38.9\text{mA}/\text{cm}^2$, an open circuit voltage of 0.41V and a fill factor of 61 percent.

"This is a big win for us. We've been working toward this milestone since 2011 when we first started our research on alternative materials for thin-film photovoltaics at imec/imomec," said Marc Meuris, program manager Solliance of the alternative thin-film PV program. "Our efficiencies are the highest in Europe and approaching the world record for this type of thin-film [solar cells](#), and we look forward to further advancing R&D to help bringing to market sustainable energy sources."

The sputtering of the Cu, Zn, Sn layers was performed at Flamac (Gent), and the international glass manufacturer AGC delivered Molybdenum-on-glass substrates. Imec's thin-film solar cell activities at imomec ([imec](#)'s associated laboratory at the university of Hasselt) are integrated in the Solliance cross-border collaboration platform, and the research was partially supported by the Flemish 'Strategisch Initiatief Materialen' (SIM) SoPPoM program.

Provided by IMEC

Citation: Solliance and imec achieve 9.7% efficiency with new thin-film CZTSe solar cell (2013, July 4) retrieved 17 April 2024 from <https://phys.org/news/2013-07-solliance-imec-efficiency-thin-film-cztse.html>

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